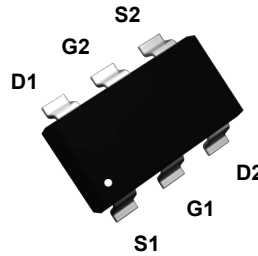
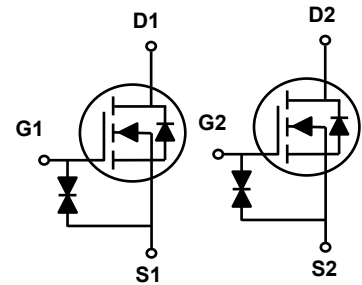


## Main Product Characteristics

$V_{DS}$	30V
$R_{DS(ON)}$	650m $\Omega$ (Max.)
$I_D$	0.7A



SOT-363



Schematic Diagram

## Features and Benefits

- Advanced MOSFET process technology
- Ideal for high efficiency switched mode power supplies
- Low on-resistance with low gate charge
- Fast switching and reverse body recovery



## Description

The GSFK03007 utilizes the latest techniques to achieve high cell density and low on-resistance. These features make this device extremely efficient and reliable for use in high efficiency switch mode power supplies and a wide variety of other applications.

## Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 10$	V
Continuous Drain Current @ Steady State ( $T_A=25^\circ\text{C}$ )	$I_D$	0.7	A
Continuous Drain Current @ Steady State ( $T_A=70^\circ\text{C}$ )		0.6	
Pulsed Drain Current <sup>1</sup>	$I_{DM}$	2.8	A
Total Power Dissipation @ Steady State ( $T_A=25^\circ\text{C}$ ) <sup>2</sup>	$P_D$	321	mW
Thermal Resistance, Junction to Ambient <sup>2</sup>	$R_{\theta JA}$	390	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To +150	$^\circ\text{C}$

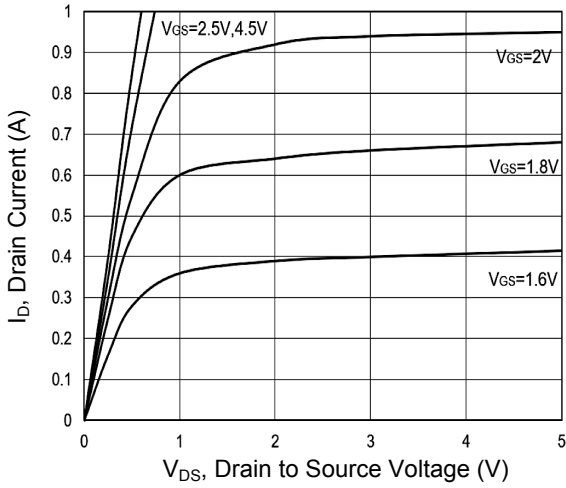

**Electrical Characteristics** ( $T_J=25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>On / Off Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	30	-	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=30V, V_{GS}=0V, T_C=25^\circ\text{C}$	-	-	1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 10V, V_{DS}=0V$	-	-	$\pm 10$	$\mu A$
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.4	-	1	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=0.2A$	-	480	650	m $\Omega$
		$V_{GS}=2.5V, I_D=0.15A$	-	600	800	
		$V_{GS}=1.8V, I_D=0.1A$	-	900	1300	
<b>Dynamic and Switching Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=15V, V_{GS}=0V, f=1\text{MHz}$	-	28	-	pF
Output Capacitance	$C_{oss}$		-	13	-	
Reverse Transfer Capacitance	$C_{rss}$		-	5.2	-	
Total Gate Charge	$Q_g$	$V_{GS}=4.5V, V_{DS}=15V, I_D=0.3A$	-	1.6	-	nC
Gate Source Charge	$Q_{gs}$		-	0.2	-	
Gate Drain Charge	$Q_{gd}$		-	0.5	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V, V_{DD}=30V, I_D=0.5A, R_{GEN}=10\Omega$	-	2	-	nS
Turn-On Rise Time	$t_r$		-	14	-	
Turn-Off Delay Time	$t_{d(off)}$		-	6	-	
Turn-Off Fall Time	$t_f$		-	9	-	
<b>Drain-Source Ratings and Characteristics</b>						
Diode Forward Voltage	$V_{SD}$	$I_S=0.7A, V_{GS}=0V$	-	0.9	1.2	V
Maximum Body-Diode Continuous Current	$I_S$	-	-	-	0.7	A

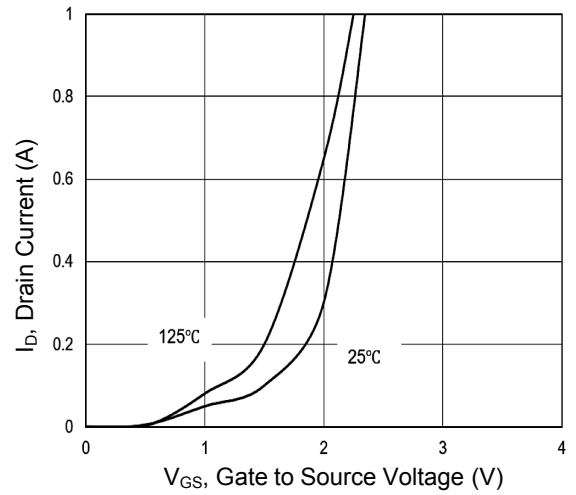
Note:

1. Pulse test: Pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .
2. Device mounted on 1" x 1" FR-4 PCB, with high coverage 2oz copper, single sided.

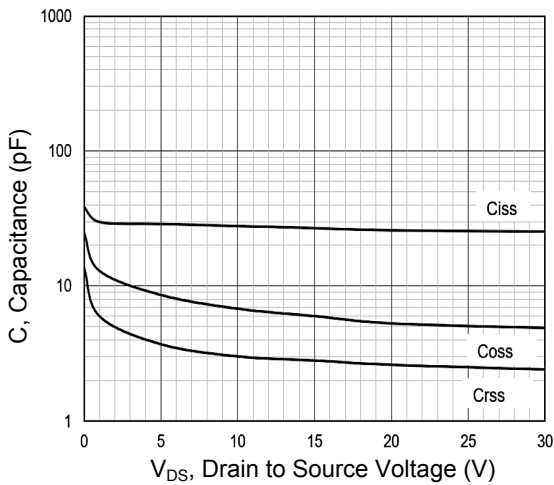
**Typical Electrical and Thermal Characteristic Curves**



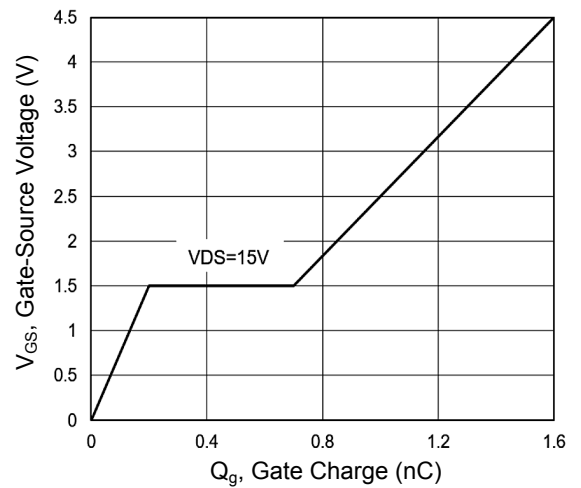
**Figure 1. Output Characteristics**



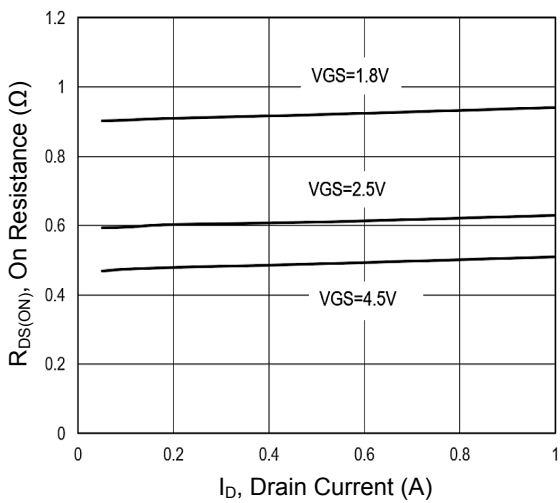
**Figure 2. Transfer Characteristics**



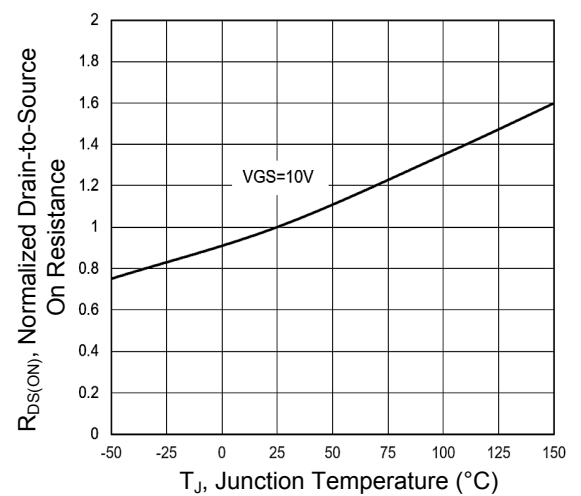
**Figure 3. Capacitance Characteristics**



**Figure 4. Gate Charge**

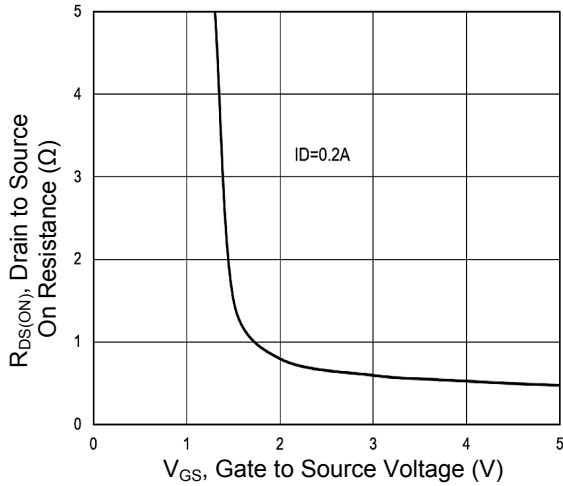


**Figure 5. Drain-Source On Resistance**

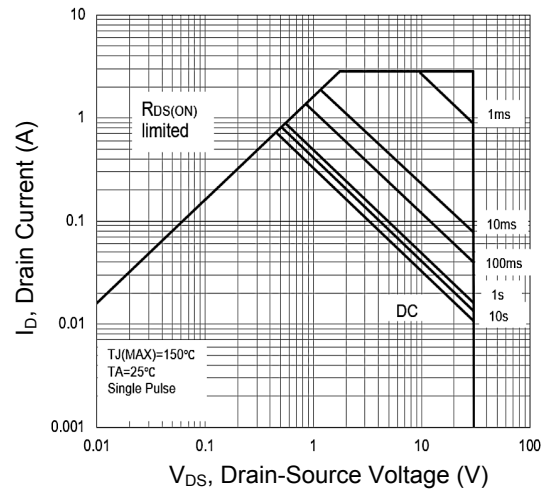


**Figure 6. Normalized On-Resistance vs. Temperature**

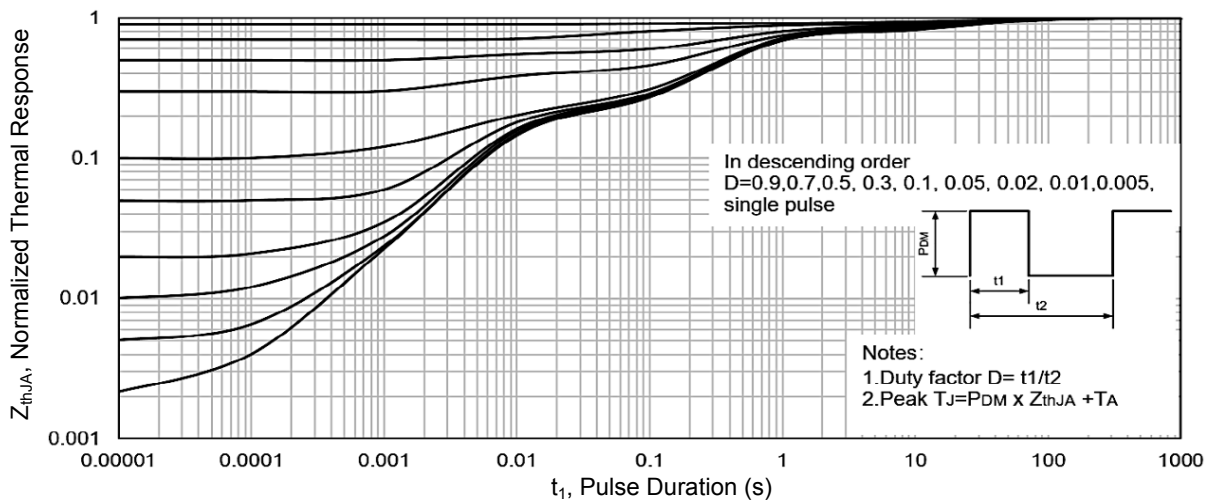
**Typical Electrical and Thermal Characteristic Curves**



**Figure 7. Typical Drain to Source On Resistance vs. Gate Voltage**

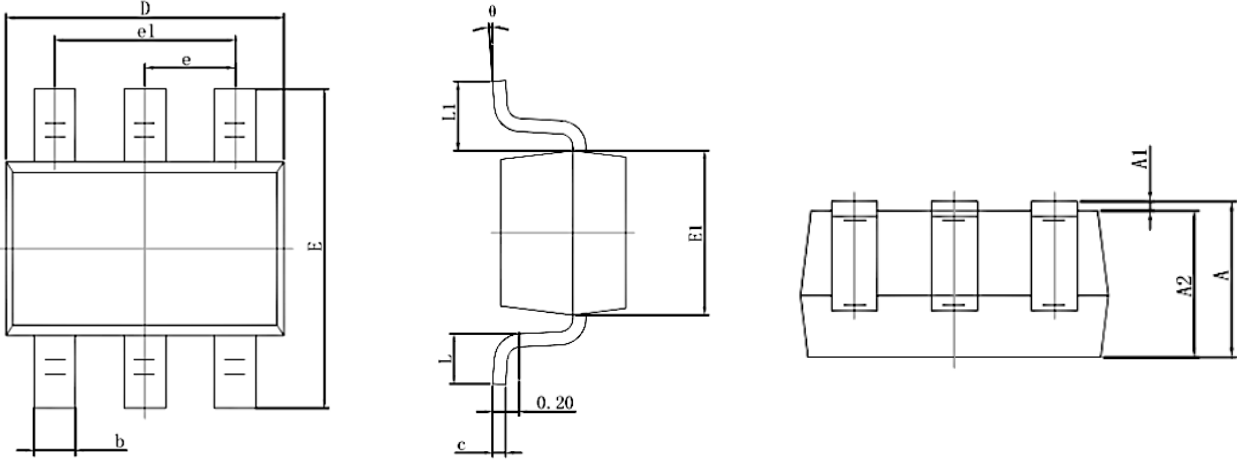


**Figure 8. Safe Operation Area**



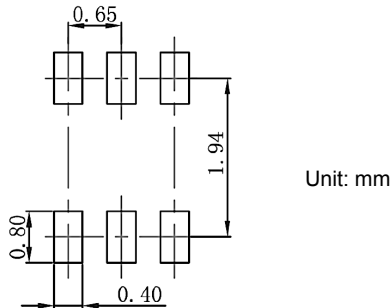
**Figure 9. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient**

**Package Outline Dimensions (SOT-363)**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.150	0.003	0.006
D	2.050	2.250	0.081	0.089
E	2.150	2.450	0.085	0.096
E1	1.150	1.350	0.045	0.053
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.260	0.460	0.010	0.018
L1	0.525 REF		0.021 REF	
θ	0°	8°	0°	8°

**Recommended Pad Layout**



**Order Information**

Device	Package	Marking	Packaging	SPQ
GSFK03007	SOT-363	N1	Tape & Reel	3,000 Pcs / Reel

For more information, please contact us at: [inquiry@goodarksemi.com](mailto:inquiry@goodarksemi.com)